

# Abstracts

## An X-Band 10 W Monolithic Transmit-Receive GaAs FET Switch

---

*Y. Ayasli, R. Mozzi, L. Hanes and L.D. Reynolds. "An X-Band 10 W Monolithic Transmit-Receive GaAs FET Switch." 1982 Microwave and Millimeter-Wave Monolithic Circuits Symposium Digest 82.1 (1982 [MCS]): 42-46.*

A monolithic transmit-receive GaAs FET switch capable of switching more than 10 W CW power with about 1 dB insertion loss and 26 dB isolation at X-band frequencies is reported.

 [Return to main document.](#)